



WBA0204B

225 – 400 MHz LOW NOISE WIDE BAND AMPLIFIER

REV A
January 2011

Key Features



- 225 – 400 MHz
- 1.40 dB Noise Figure
- 45.0 dBm Output IP₃
- 18.0 dB Gain
- +/-0.30 dB Gain Flatness
- 30.0 dBm P_{1dB}
- 1.5:1 VSWR
- Single Power Supply
- >68 Years MTBF
- Unconditional Stable
- RoHS compliant

Product Description

WBA0204B integrates WanTcom proprietary low noise amplifier technology, high frequency micro electronic assembly techniques, and high reliability design to realize optimum low noise figure, wideband, high linearity, and unconditional stable performances together. With single +10.0V DC operation, the amplifier has optimal input and output matching in the specified frequency range at 50-Ohm impedance system. The amplifier has SMA connectorized housing.

The amplifier is designed to meet the rugged standard of MIL-STD-202.

Applications

- Mobile Infrastructures
- VHF
- CATV/DBS
- Defense
- Security System
- Measurement
- Fixed Wireless

Specifications

Summary of the electrical specifications WBA0204B at room temperature

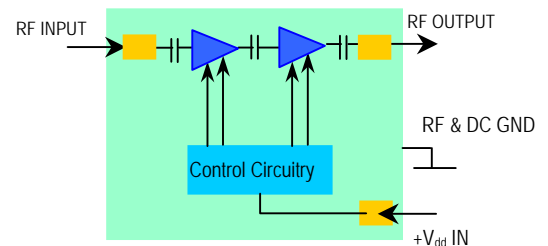
Index	Testing Item	Symbol	Test Constraints	Min	Nom	Max	Unit
1	Gain	S ₂₁	0.225 – 0.40 GHz	17.0	18.0	19.0	dB
2	Gain Variation	ΔG	0.225 – 0.40 GHz		+/- 0.3	+/-0.5	dB
3	Input VSWR	SWR ₁	0.225 – 0.40 GHz		1.5:1	1.8:1	Ratio
4	Output VSWR	SWR ₂	0.225 – 0.40 GHz		1.25:1	1.35:1	Ratio
5	Reverse Isolation	S ₁₂	0.225 – 0.40 GHz		25		dB
6	Noise figure	NF	0.225 – 0.40 GHz		1.40	1.60	dB
7	Output Power 1dB compression Point	P _{1dB}	0.225 – 0.40 GHz	28	30		dBm
8	Output-Third-Order Interception point	IP ₃	Two-Tone, P _{out} +10 dBm each, 1 MHz separation	43	45		dBm
9	Current Consumption	I _{dd}	V _{dd} = +10 V		220		mA
10	Power Supply Voltage	V _{dd}		+12	+15	+18	V
11	Thermal Resistance	R _{th,c}	Junction to case			30	°C/W
12	Operating Temperature	T _o		0		+70	°C
13	Maximum Average RF Input Power	P _{IN, MAX}	DC ~ 6 GHz			33	dBm

Absolute Maximum Ratings

Parameters	Units	Ratings
DC Power Supply Voltage	V	20
Drain Current	mA	250
Total Power Dissipation	mW	2500
RF Input Power	dBm	27
Channel Temperature	°C	150
Storage Temperature	°C	-55 ~ 125
Operating Temperature	°C	-40 ~ 85
Thermal Resistance	°C/W	30

Operation of this device above any one of these parameters may cause permanent damage.

Functional Block Diagram



Ordering Information

Model Number	WBA0204B
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Specifications and information are subject to change without notice.

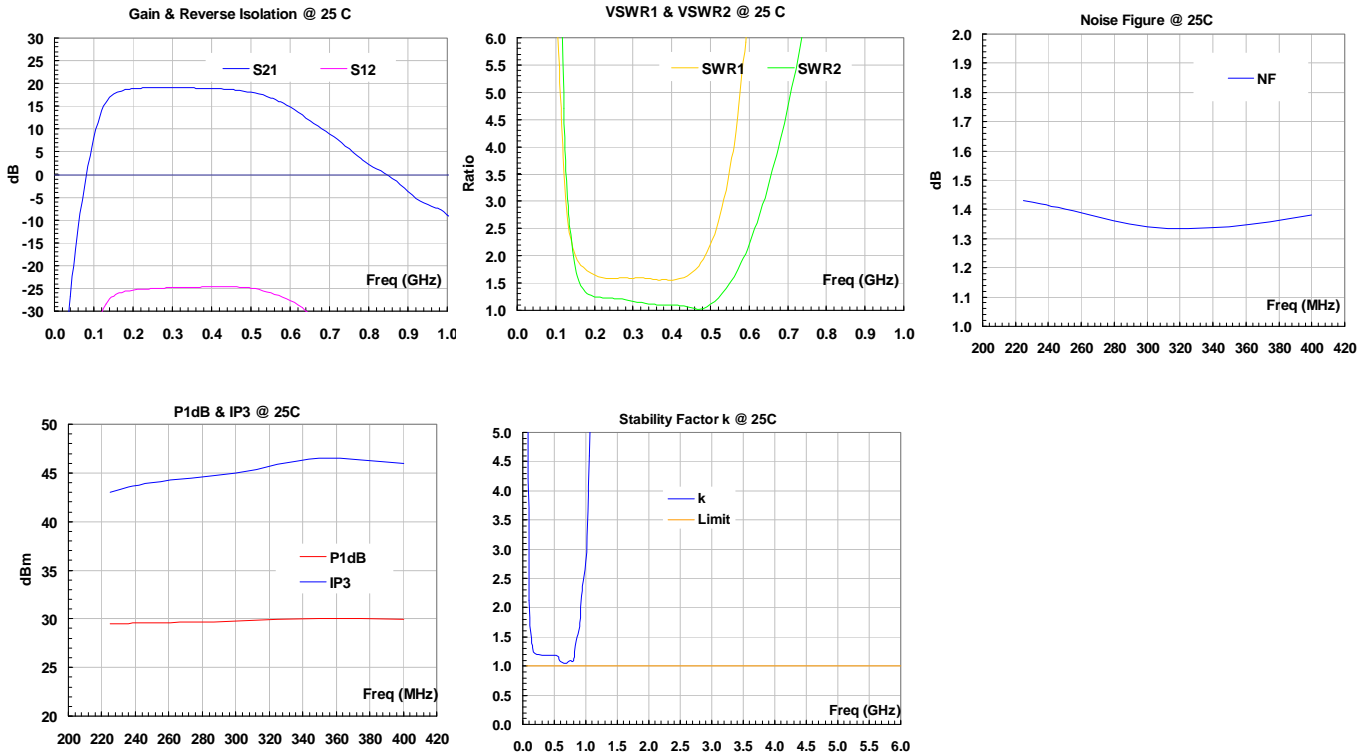


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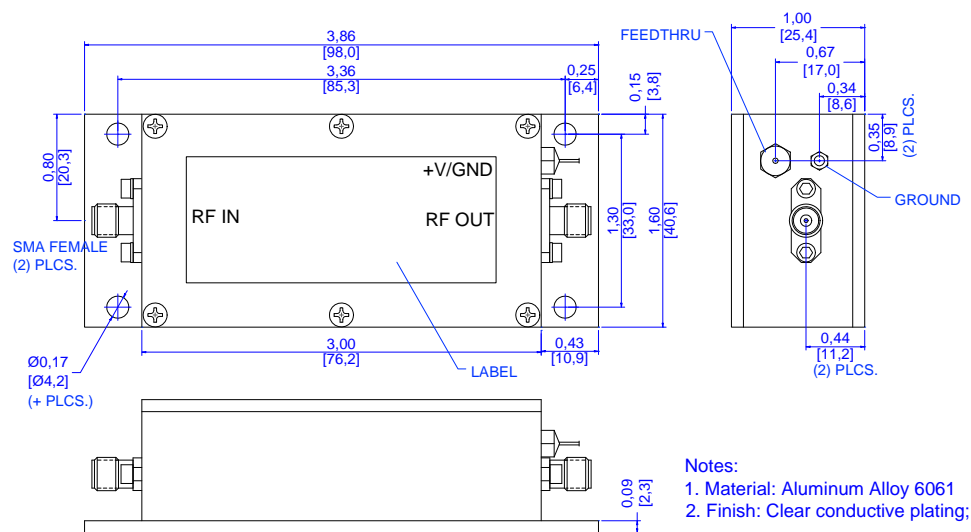
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Typical Data



Outline,



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Application Notes:

A. SMA Torque Wrench Selection

Always use a torque wrench with 5 ~ 6 inch-lb coupling torque setting for mating the SMA cables to the amplifier. Never use torque more than 8 inch-lb wrench for tightening the mating cable to the connector. Otherwise, the permanent damage will occur to the SMA connectors of the amplifier. 8710-1582 (5 inch-lb) is one of the ideal torque wrench choice from Agilent Technology.

B. DC Power Line Connection

Strip the insulation layer at the end of DC power supply wire. The stripped distance should be in the range of 0.100" to 0.200". The 24 ~ 26 American Wire Gauge wire is suitable. Wound the stripped terminal wire about 1 to 2 turns on the DC feed thru center pin. Solder the wounded wire and the center pin together. Clean the soldering area by Q-tip with alcohol to remove the flux and residue.

Repeat the process to solder the DC return wire on the ground turret.
